

RJF0409JSP

40V, 5A Silicon N Channel Thermal FET Power Switching

R07DS1228EJ0300 Rev.3.00 Jul 28, 2015

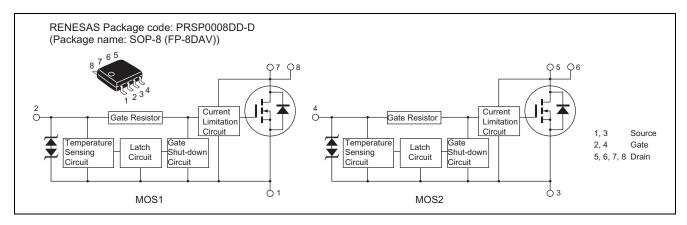
Description

This FET has the over temperature shut-down capability sensing to the junction temperature. This FET has the built-in over temperature shut-down circuit in the gate area. And this circuit operation to shut-down the gate voltage in case of high junction temperature like applying over power consumption, over current etc..

Features

- Logic level operation (4 V Gate drive).
- Built-in the over temperature shut-down circuit.
- High endurance capability against to the short circuit.
- Latch type shut down operation (need 0 voltage recovery).
- Built-in the current limitation circuit.
- High density mounting
- Power supply voltage applies 12 V.
- AEC-Q101 Compliant

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	40	V
Gate to source voltage	V _{GSS}	16	V
Gate to source voltage	V_{GSS}	-2.5	V
Drain current	I _D Note4	5	Α
Body-drain diode reverse drain current	I _{DR}	5	А
Avalanche current	I _{AP} Note 3	1.5	Α
Avalanche energy	E _{AR} Note 3	15	mJ
Channel dissipation	Pch Note 1	1	W
Channel dissipation	Pch Note 2	1.5	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. 1 Drive operation: When using the glass epoxy board (FR4 $40 \times 40 \times 1.6$ mm), PW ≤ 10 s

- 2. 2 Drive operation : When using the glass epoxy board (FR4 40 \times 40 \times 1.6 mm), PW \leq 10 s
- 3. Tch = 25°C, Rg \geq 50 Ω
- 4. It provides by the current limitation lower bound value.

Typical Operation Characteristics

 $(Ta = 25^{\circ}C)$

Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Input voltage	V _{IH}	3.5	_	_	V	
	V _{IL}	_	_	1.2	V	
Input current	I _{IH1}		_	100	μΑ	Vi = 8 V, V _{DS} = 0
(Gate non shut down)	I _{IH2}		_	50	μΑ	$Vi = 3.5 V, V_{DS} = 0$
	I⊫		_	1	μΑ	Vi = 1.2 V, V _{DS} = 0
Input current	I _{IH(sd)1}		0.8	_	mA	Vi = 8 V, V _{DS} = 0
(Gate shut down)	I _{IH(sd)2}		0.35	_	mA	$Vi = 3.5 V, V_{DS} = 0$
Shut down temperature	Tsd		175	_	°C	Channel temperature
Gate operation voltage	Vop	3.5	_	12	V	
Drain current	I _{D limt}	5	_	_	Α	V _{GS} = 5 V, V _{DS} = 10 V Note 5
(Current limitation value)						

Notes: 5. Pulse test

Electrical Characteristics

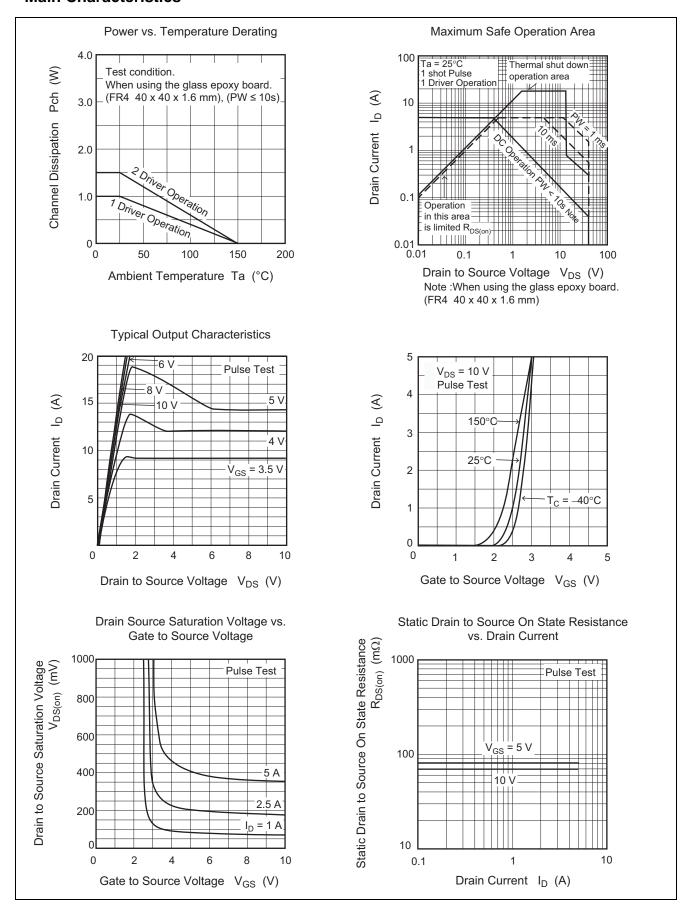
 $(Ta = 25^{\circ}C)$

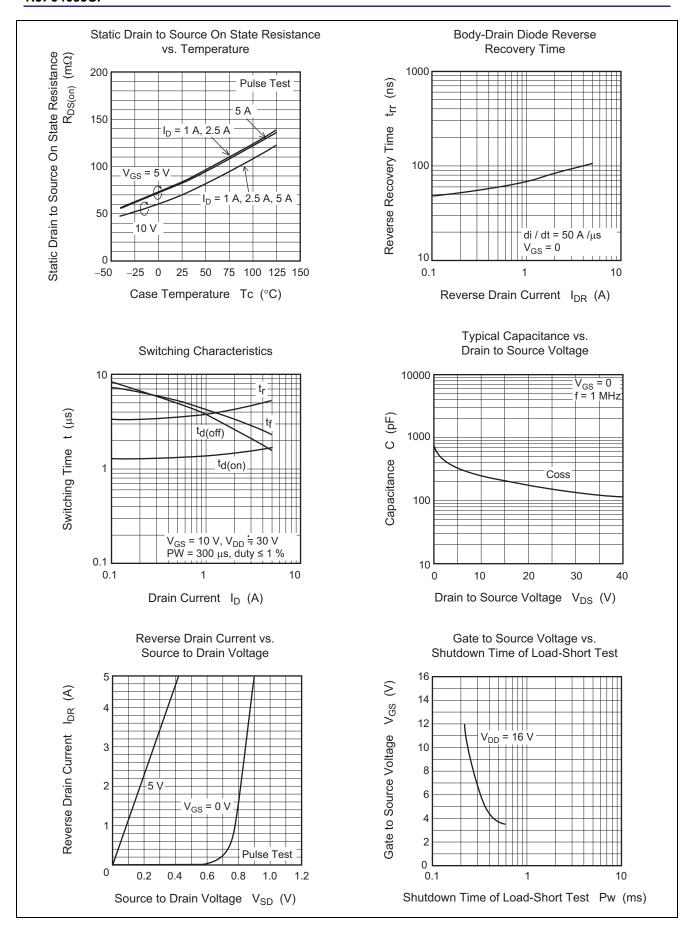
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain current	I _{D1}	_	_	14	Α	V _{GS} = 3.5 V, V _{DS} = 10 V Note 6
	I _{D2}	_	_	10	mA	V _{GS} = 1.2 V, V _{DS} = 10 V
	I _{D3}	5	_	_	Α	V _{GS} = 5 V, V _{DS} = 10 V Note 6
Drain to source breakdown voltage	V _{(BR)DSS}	40	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown	V _{(BR)GSS}	16	_	_	V	$I_G = 800 \ \mu A, \ V_{DS} = 0$
voltage	$V_{(BR)GSS}$	-2.5	_	_	V	$I_G = -100 \mu A, V_{DS} = 0$
Gate to source leak current	I _{GSS1}	_	_	100	μΑ	$V_{GS} = 8 \text{ V}, V_{DS} = 0$
	I _{GSS2}	_	_	50	μΑ	$V_{GS} = 3.5 \text{ V}, V_{DS} = 0$
	I _{GSS3}	_	_	1	μΑ	V _{GS} = 1.2 V, V _{DS} = 0
	I _{GSS4}	_	_	-100	μΑ	V _{GS} =- 2.4 V, V _{DS} = 0
Input current (shut down)	I _{GS(OP)1}	_	0.8	_	mA	$V_{GS} = 8 \text{ V}, V_{DS} = 0$
	I _{GS(OP)2}	_	0.35	_	mA	$V_{GS} = 3.5 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	10	μА	$V_{DS} = 32 \text{ V}, V_{GS} = 0$ Ta = 125°C
Gate to source cutoff voltage	V _{GS(off)}	1.1	_	2.1	V	I _D = 1 mA, V _{DS} = 10 V
Forward transfer admittance	y _{fs}	4	7	_	S	I _D = 2.5 A, V _{DS} = 10 V
Static drain to source on state	R _{DS(on)}	_	81	100	mΩ	I _D = 2.5 A, V _{GS} = 5 V Note 6
resistance	R _{DS(on)}	_	70	86	mΩ	I _D = 2.5 A, V _{GS} = 10 V Note 6
Output capacitance	Coss	_	245	_	pF	V _{DS} = 10 V, V _{GS} = 0, f = 1MHz
Turn-on delay time	t _{d(on)}	_	1.65	_	μS	I _D = 2.5 A, V _{GS} = 10 V
Rise time	tr	_	4.50	_	μS	$R_L = 12 \Omega$
Turn-off delay time	t _{d(off)}	_	2.35	_	μS	
Fall time	t _f	_	3.0	_	μS	
Body-drain diode forward voltage	V_{DF}	_	0.89	_	V	I _F = 5 A, V _{GS} = 0 Note 6
Body-drain diode reverse recovery time	t _{rr}	_	106	_	ns	$I_F = 5 \text{ A}, V_{GS} = 0$ $di_F/dt = 50 \text{ A}/\mu\text{s}$
Over load shut down operation time Note 7	tos	_	0.37	_	ms	V _{GS} = 5 V, V _{DD} = 16 V

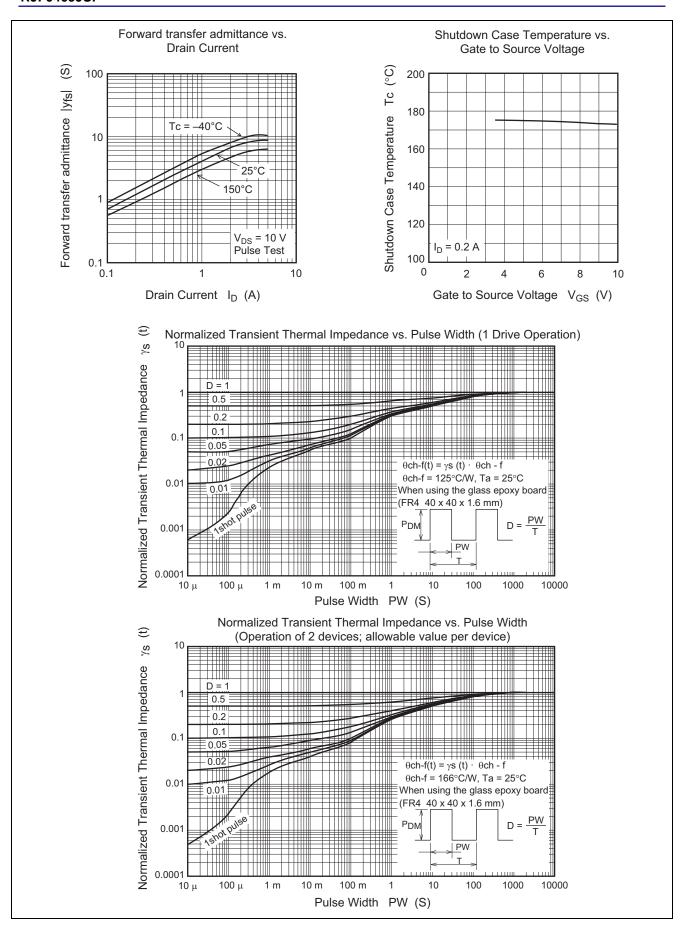
Notes: 6. Pulse test

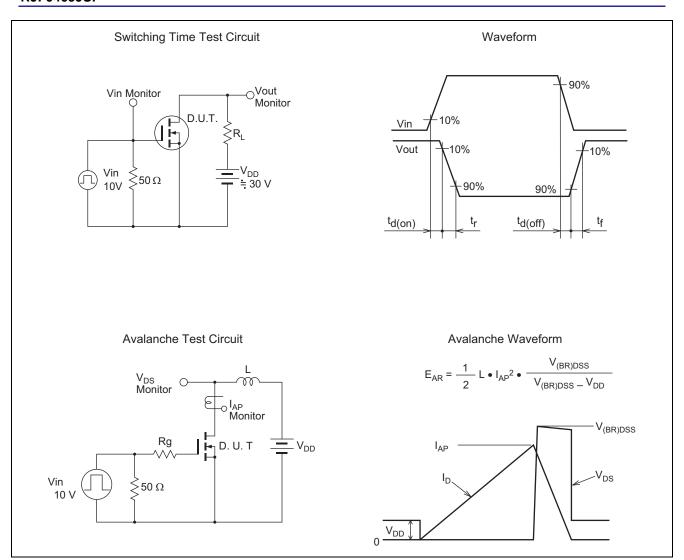
7. Including the junction temperature rise of the over loaded condition.

Main Characteristics

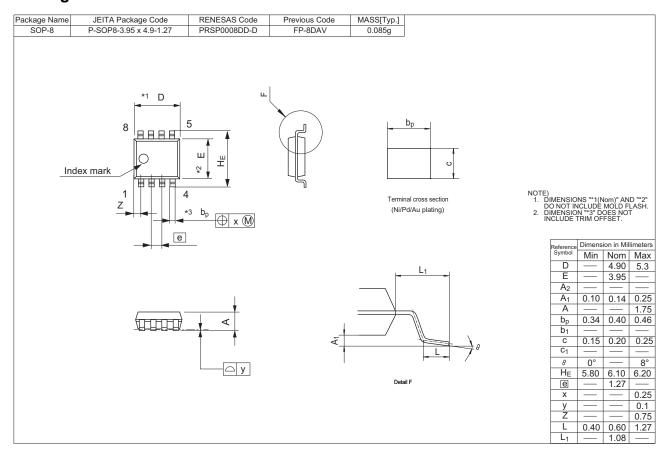








Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJF0409JSP-00-J0	2500 pcs/reel	Taping

Note: The symbol of 2nd "-" is occasionally presented as "#".

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